March 1993

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# FAIRCHILD

SEMICONDUCTOR®

# 74LVX14 Low Voltage Hex Inverter with Schmitt Trigger Input

**Features** 

■ Input voltage level translation from 5V to 3V

dynamic threshold performance

■ Ideal for low power/low noise 3.3V applications

■ Guaranteed simultaneous switching noise level and

#### **General Description**

The LVX14 contains six inverter gates each with a Schmitt trigger input. They are capable of transforming slowly changing input signals into sharply defined, jitter-free output signals. In addition, they have a greater noise margin than conventional inverters.

The LVX14 has hysteresis between the positive-going and negative-going input thresholds (typically 1.0V) which is determined internally by transistor ratios and is essentially insensitive to temperature and supply voltage variations.

The inputs tolerate voltages up to 7V allowing the interface of 5V systems to 3V systems.

## **Ordering Code:**

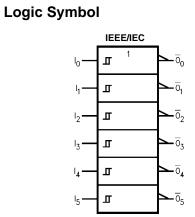
#### Package Order Number Package Description Number 74LVX14M 14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow M14A 74LVX14MX\_NL Pb-Free 14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow M14A Pb-Free 14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide 74LVX14SJ M14D 74LVX14MTC MTC14 14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide 74LVX14MTCX NL MTC14 Pb-Free 14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm (Note 1) Wide

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Pb-Free package per JEDEC J-STD-020B.

Note 1: "\_NL" indicates Pb-Free package (per JEDEC J-STD-020B). Device available in Tape and Reel only.

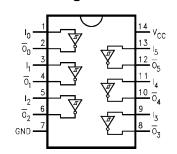
# 74LVX14



# Pin Descriptions

Pin Names	Description
I <sub>n</sub>	Inputs
Ōn	Outputs

# **Connection Diagram**



# Truth Table

Input	Output
А	ō
L	Н
н	L

#### Absolute Maximum Ratings(Note 2)

Supply Voltage (V <sub>CC</sub> ) DC Input Diode Current (I <sub>IK</sub> )	-0.5V to +7.0V
$V_{\rm I} = -0.5V$	–20 mA
DC Input Voltage (V <sub>I</sub> )	-0.5V to 7V
DC Output Diode Current (I <sub>OK</sub> )	
$V_{O} = -0.5V$	–20 mA
$V_O = V_{CC} + 0.5V$	+20 mA
DC Output Voltage (V <sub>O</sub> )	-0.5V to V <sub>CC</sub> + 0.5V
DC Output Source	
or Sink Current (I <sub>O</sub> )	±25 mA
DC V <sub>CC</sub> or Ground Current	
(I <sub>CC</sub> or I <sub>GND</sub> )	±50 mA
Storage Temperature (T <sub>STG</sub> )	-65°C to +150°C
Power Dissipation	180 mW

#### Recommended Operating Conditions (Note 3)

2.0V to 3.6V
0V to 5.5V
0V to V <sub>CC</sub>
-40°C to +85°C

Note 2: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: Unused inputs must be held HIGH or LOW. They may not float.

# **DC Electrical Characteristics**

Symbol	Parameter Positive Threshold	Vcc	$T_A = +25^{\circ}C$			$\textbf{T}_{\textbf{A}}=-40^{\circ}\textbf{C} \text{ to }+85^{\circ}\textbf{C}$		Units	Conditions					
		•00	Min	Тур	Max	Min	Max	onno	Conditions					
V <sub>t</sub> +		3.0	3.0	3.0	3.0	3.0	3.0	3.0			2.2		2.2	V
V <sub>t</sub> -	Negative Threshold	3.0	0.9			0.9		V						
V <sub>H</sub>	Hysteresis	3.0	0.3		1.2	0.3	1.2	V						
V <sub>OH</sub>	HIGH Level	2.0	1.9	2.0		1.9			I <sub>OH</sub> = -50 μA					
	Output Voltage	3.0	2.9	3.0		2.9		V	$V_{IN} = V_{IL} \text{ or } V_{IH}  \begin{matrix} I_{OH} = -50 \ \mu A \\ I_{OH} = -50 \ \mu A \\ I_{OH} = -4 \ m A \end{matrix}$					
		3.0	2.58			2.48			I <sub>OH</sub> = -4 mA					
V <sub>OL</sub>	LOW Level	2.0		0.0	0.1		0.1		I <sub>OL</sub> = 50 μA					
	Output Voltage	3.0		0.0	0.1		0.1	V	$V_{IN} = V_{IL} \text{ or } V_{IH}$ $I_{OL} = 50 \ \mu A$ $I_{OL} = 4 \ m A$					
		3.0			0.36		0.44		I <sub>OL</sub> = 4 mA					
I <sub>IN</sub>	Input Leakage Current	3.6			±0.1		±1.0	μA	V <sub>IN</sub> = 5.5V or GND					
I <sub>CC</sub>	Quiescent Supply Current	3.6			2.0		20	μA	V <sub>IN</sub> = V <sub>CC</sub> or GND					

### Noise Characteristics (Note 4)

Parameter	V <sub>cc</sub>	T <sub>A</sub> =	25°C	Units	C <sub>L</sub> (pF)	
	(V)	Тур	Limit	Onits	0 <sub>L</sub> (pi )	
Quiet Output Maximum Dynamic V <sub>OL</sub>	3.3	0.3	0.5	V	50	
Quiet Output Minimum Dynamic V <sub>OL</sub>	3.3	-0.3	-0.5	V	50	
Minimum HIGH Level Dynamic Input Voltage	3.3		2.0	V	50	
Maximum LOW Level Dynamic Input Voltage			0.8	V	50	
	Quiet Output Maximum Dynamic V <sub>OL</sub> Quiet Output Minimum Dynamic V <sub>OL</sub> Minimum HIGH Level Dynamic Input Voltage	Parameter (V)   Quiet Output Maximum Dynamic V <sub>OL</sub> 3.3   Quiet Output Minimum Dynamic V <sub>OL</sub> 3.3   Minimum HIGH Level Dynamic Input Voltage 3.3	Parameter Typ   Quiet Output Maximum Dynamic V <sub>OL</sub> 3.3 0.3   Quiet Output Minimum Dynamic V <sub>OL</sub> 3.3 -0.3   Minimum HIGH Level Dynamic Input Voltage 3.3 -0.3	Parameter Typ Limit   Quiet Output Maximum Dynamic V <sub>OL</sub> 3.3 0.3 0.5   Quiet Output Minimum Dynamic V <sub>OL</sub> 3.3 -0.3 -0.5   Minimum HIGH Level Dynamic Input Voltage 3.3 2.0	Parameter Image: Constraint of the second seco	

Note 4: Input t<sub>r</sub> = t<sub>f</sub> = 3ns

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# **AC Electrical Characteristics**

Symbol	Parameter	V <sub>cc</sub>	$T_A = +25^{\circ}C$			$T_A = -40^\circ$	C to +85°C	Units	C <sub>L</sub> (pF)
		(V)	Min	Тур	Max	Min	Max	Onita	( )
t <sub>PLH</sub>	Propagation	2.7		8.7	16.3	1.0	19.5		15
t <sub>PHL</sub>	Delay Time	2.1		11.2	19.8	1.0	23.0	ns	50
		$3.3\pm0.3$		6.8	10.6	1.0	12.5	115	15
		<b>5.5</b> ± 0.5		9.3	14.1	1.0	16.0		50
t <sub>OSLH</sub>	Output to Output	2.7			1.5		1.5	ns	50
t <sub>OSHL</sub>	Skew (Note 5)	3.3			1.5		1.5	115	50

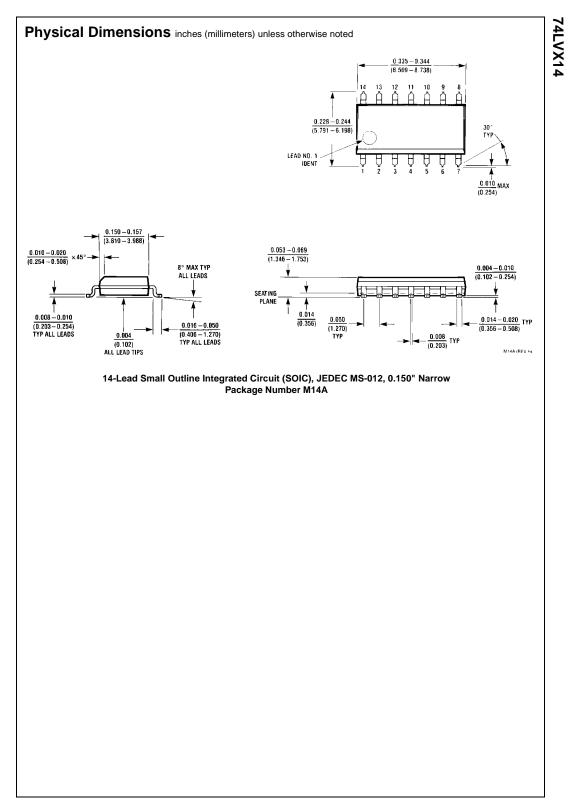
Note 5: Parameter guaranteed by design.  $t_{OSLH} = |t_{PLHm} - t_{PLHn}|, t_{OSHL} = |t_{PHLm} - t_{PHLn}|$ 

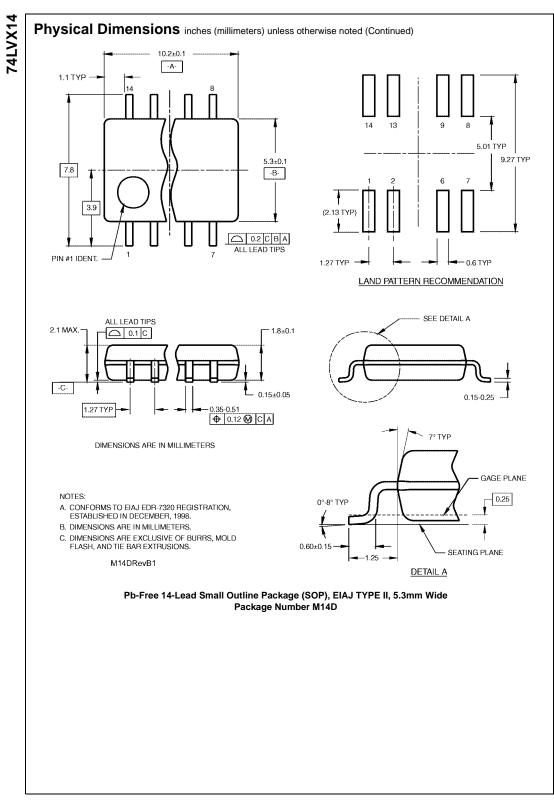
### Capacitance

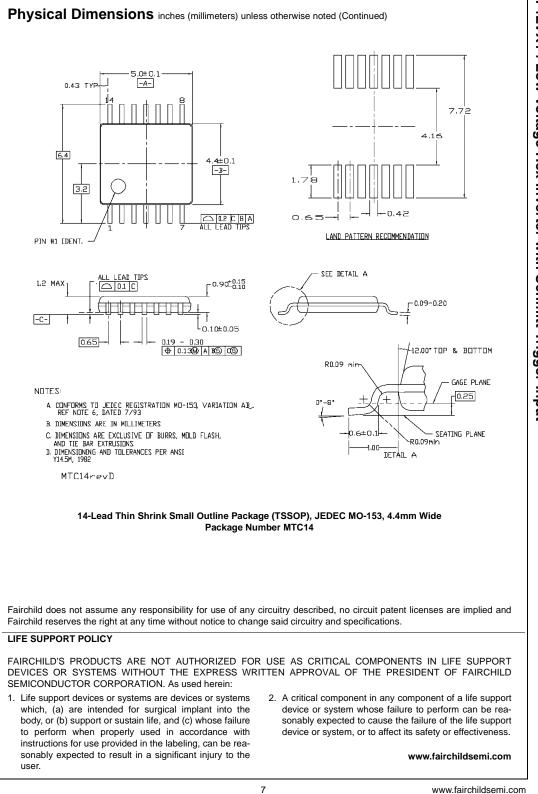
Symbol	Parameter		T <sub>A</sub> = +25°C		$T_A = -40^{\circ}$	Units		
	i arameter	Min	Тур	Max	Min	Max	Onits	
CIN	Input Capacitance		4	10		10	pF	
C <sub>PD</sub>	Power Dissipation		- 24		24			- <b>F</b>
Capacitance (Note 6)			21				pF	

Note 6: CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:  $I_{CC(opr.)} = \frac{C_{PD} \times V_{CC} \times f_{IN} + I_{CC}}{6 \text{ (per Gate)}}$ 







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